

# 74AUP1G373

Low-power D-type transparent latch; 3-state

Rev. 6 — 4 July 2012

Product data sheet

## 1. General description

The 74AUP1G373 provides the single D-type transparent latch with 3-state output. While the latch-enable (LE) input is high, the Q output follows the data (D) input. When pin LE is LOW, the latch stores the information that was present at the D-input one set-up time preceding the HIGH-to-LOW transition of pin LE. When pin  $\overline{OE}$  is LOW, the contents of the latch is available at the (Q) output. When pin  $\overline{OE}$  is HIGH, the output goes to the high-impedance OFF-state. Operation of input pin  $\overline{OE}$  does not affect the state of the latch.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

## 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - ◆ JESD8-12 (0.8 V to 1.3 V)
  - ◆ JESD8-11 (0.9 V to 1.65 V)
  - ◆ JESD8-7 (1.2 V to 1.95 V)
  - ◆ JESD8-5 (1.8 V to 2.7 V)
  - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from  $-40^{\circ}C$  to  $+85^{\circ}C$  and  $-40^{\circ}C$  to  $+125^{\circ}C$



### 3. Ordering information

**Table 1. Ordering information**

Type number	Package				Version
	Temperature range	Name	Description	Version	
74AUP1G373GW	−40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363	
74AUP1G373GM	−40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886	
74AUP1G373GF	−40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891	
74AUP1G373GN	−40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115	
74AUP1G373GS	−40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202	

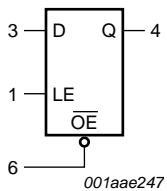
### 4. Marking

**Table 2. Marking**

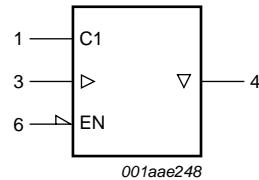
Type number	Marking code <sup>[1]</sup>
74AUP1G373GW	aW
74AUP1G373GM	aW
74AUP1G373GF	aW
74AUP1G373GN	aW
74AUP1G373GS	aW

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

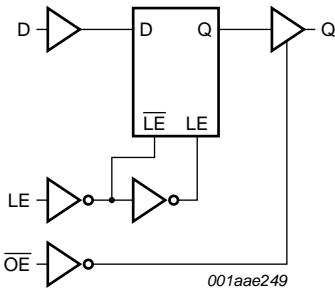
### 5. Functional diagram



**Fig 1. Logic symbol**



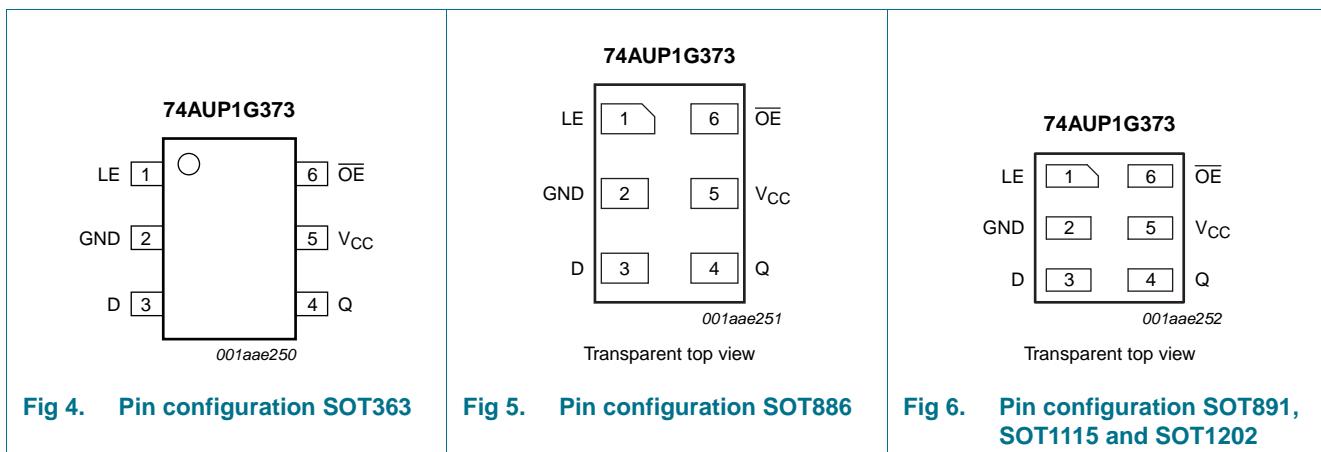
**Fig 2. IEC logic symbol**



**Fig 3. Logic diagram**

## 6. Pinning information

### 6.1 Pinning



### 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
LE	1	latch enable input (active HIGH)
GND	2	ground (0 V)
D	3	data input
Q	4	latch output
V <sub>CC</sub>	5	supply voltage
OE	6	output enable input (active LOW)

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

Operating modes	Input			Internal latch	Output
	OE	LE	D		
Enable and read register (transparent mode)	L	H	L	L	L
	L	H	H	H	H
Latch and read register	L	L	I	L	L
	L	L	h	H	H
Latch register and disable outputs	H	X	X	X	Z

[1] H = HIGH voltage level;

h = HIGH voltage level one setup time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level;

I = LOW voltage level one setup time prior to the HIGH-to-LOW LE transition;

X = Don't care;

Z = high-impedance OFF-state.

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
V <sub>I</sub>	input voltage		[1] -0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
V <sub>O</sub>	output voltage	Active mode and Power-down mode	[1] -0.5	+4.6	V
I <sub>O</sub>	output current	V <sub>O</sub> = 0 V to V <sub>CC</sub>	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>STG</sub>	storage temperature		-65	+150	°C
P <sub>TOT</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2] -	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 packages: above 87.5 °C the value of P<sub>TOT</sub> derates linearly with 4.0 mW/K.

For XSON6 packages: above 118 °C the value of P<sub>TOT</sub> derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
V <sub>I</sub>	input voltage		0	3.6	V
V <sub>O</sub>	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>AMB</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	-	200	ns/V

## 10. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>AMB</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 $\mu$ A; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 $\times$ V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 $\mu$ A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 $\times$ V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	$\pm$ 0.1	$\mu$ A
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	$\pm$ 0.1	$\mu$ A
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	$\pm$ 0.2	$\mu$ A
$\Delta$ I <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	$\pm$ 0.2	$\mu$ A
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.5	$\mu$ A
$\Delta$ I <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	[1]	-	40	$\mu$ A
C <sub>I</sub>	input capacitance	V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>	-	0.8	-	pF
C <sub>O</sub>	output capacitance	output enabled; V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.7	-	pF
		output disabled; V <sub>CC</sub> = 0 V to 3.6 V; V <sub>O</sub> = GND or V <sub>CC</sub>	-	1.5	-	pF

T<sub>amb</sub> = -40 °C to +85 °C

V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 $\times$ V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 $\times$ V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 $\times$ V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 $\times$ V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 $\mu$ A; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 $\times$ V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 $\mu$ A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 $\times$ V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	$\pm$ 0.5	$\mu$ A
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	$\pm$ 0.5	$\mu$ A
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	$\pm$ 0.5	$\mu$ A
$\Delta$ I <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	$\pm$ 0.6	$\mu$ A
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.9	$\mu$ A
$\Delta$ I <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	[1]	-	50	$\mu$ A
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.75 $\times$ V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.70 $\times$ V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.25 $\times$ V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30 $\times$ V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	µA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.75	µA
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	1.4	µA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	[1]	-	75	µA

[1] One input at V<sub>CC</sub> - 0.6 V, other input at V<sub>CC</sub> or GND.

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C				Unit
			Min	Typ <sup>[1]</sup>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
<b>C<sub>L</sub> = 5 pF</b>										
t <sub>pd</sub>	propagation delay	D to Q; see <a href="#">Figure 7</a>	[2]							
		V <sub>CC</sub> = 0.8 V	-	21.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.8	6.6	13.5	2.6	13.8	2.6	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.4	4.6	7.8	2.1	8.3	2.1	9.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.7	6.2	1.6	6.7	1.6	7.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	2.9	4.1	1.5	4.5	1.5	4.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	2.5	3.5	1.2	4.0	1.2	4.5	ns
		LE to Q; see <a href="#">Figure 8</a>	[2]							
		V <sub>CC</sub> = 0.8 V	-	20.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.7	6.2	13.6	2.5	14.0	2.5	15.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.4	7.6	2.0	8.5	2.0	9.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.8	3.5	5.8	1.5	6.7	1.5	7.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	2.6	4.0	1.3	4.4	1.3	4.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	2.2	3.3	1.1	3.8	1.1	4.2	ns
t <sub>en</sub>	enable time	OE to Q; see <a href="#">Figure 10</a>	[3]							
		V <sub>CC</sub> = 0.8 V	-	17.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.2	5.1	9.2	3.0	9.2	3.0	10.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.6	3.8	5.8	2.4	6.1	2.4	6.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	3.3	4.8	2.0	5.0	2.0	5.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.0	2.7	3.8	1.8	4.0	1.8	4.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.9	2.5	3.4	1.8	3.6	1.8	4.0	ns
t <sub>dis</sub>	disable time	OE to Q; see <a href="#">Figure 10</a>	[4]							
		V <sub>CC</sub> = 0.8 V	-	9.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.9	4.2	7.5	2.8	7.9	2.8	8.7	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	3.2	4.9	2.1	5.3	2.1	5.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	3.0	4.4	2.1	4.9	2.1	5.4	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	2.2	3.1	1.5	3.4	1.5	3.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.9	2.6	3.3	1.8	3.6	1.8	4.0	ns

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C				Unit
			Min	Typ <sup>[1]</sup>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
<b><math>C_L = 10 \text{ pF}</math></b>										
$t_{pd}$	propagation delay	D to Q; see <a href="#">Figure 7</a>	<sup>[2]</sup>							
		$V_{CC} = 0.8 \text{ V}$	-	24.4	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.0	7.5	15.3	2.7	15.9	2.7	17.4	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	2.6	5.3	9.0	2.2	9.4	2.2	10.3	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.5	4.3	6.9	2.1	7.3	2.1	8.0	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.0	3.5	4.8	1.8	5.3	1.8	5.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.8	3.1	4.2	1.7	4.6	1.7	5.1	ns
		LE to Q; see <a href="#">Figure 8</a>	<sup>[2]</sup>							
		$V_{CC} = 0.8 \text{ V}$	-	23.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	2.9	7.1	15.4	2.7	16.1	2.7	17.7	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	2.5	5.0	8.8	2.1	9.5	2.1	10.4	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.3	4.1	6.6	2.0	7.3	2.0	8.1	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.9	3.1	4.7	1.6	5.2	1.6	5.8	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.7	2.8	4.0	1.4	4.4	1.4	4.9	ns
$t_{en}$	enable time	$\overline{OE}$ to Q; see <a href="#">Figure 10</a>	<sup>[3]</sup>							
		$V_{CC} = 0.8 \text{ V}$	-	21.2	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.7	6.0	10.6	3.4	10.6	3.4	11.7	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.1	4.5	6.7	2.8	7.0	2.8	7.7	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.7	3.9	5.5	2.5	5.8	2.5	6.4	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.4	3.3	4.5	2.2	4.7	2.2	5.2	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.3	3.1	4.1	2.2	4.3	2.2	4.7	ns
$t_{dis}$	disable time	$\overline{OE}$ to Q; see <a href="#">Figure 10</a>	<sup>[4]</sup>							
		$V_{CC} = 0.8 \text{ V}$	-	11.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.9	5.3	8.7	3.8	9.2	3.8	10.1	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.0	4.1	5.8	2.9	6.2	2.9	6.8	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.2	4.2	5.7	3.1	6.0	3.1	6.6	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.3	3.0	4.0	2.2	4.3	2.2	4.7	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	3.0	3.8	4.7	2.9	5.0	2.9	5.5	ns

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C				Unit
			Min	Typ <sup>[1]</sup>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
<b><math>C_L = 15 \text{ pF}</math></b>										
$t_{pd}$	propagation delay	D to Q; see <a href="#">Figure 7</a>	<a href="#">[2]</a>							
		$V_{CC} = 0.8 \text{ V}$	-	27.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.5	8.3	16.9	3.2	17.5	3.2	19.2	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.1	5.9	9.6	2.7	10.5	2.7	11.6	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.6	4.8	7.6	2.2	8.5	2.2	9.3	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.5	3.9	5.5	2.2	5.9	2.2	6.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.2	3.6	4.9	1.8	5.5	1.8	6.0	ns
		LE to Q; see <a href="#">Figure 8</a>	<a href="#">[2]</a>							
		$V_{CC} = 0.8 \text{ V}$	-	26.1	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.3	7.9	17.3	3.0	18.0	3.0	19.8	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.0	5.6	9.7	2.5	10.7	2.5	11.8	ns
$t_{en}$	enable time	$\overline{OE}$ to Q; see <a href="#">Figure 10</a>	<a href="#">[3]</a>							
		$V_{CC} = 0.8 \text{ V}$	-	24.6	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	4.1	6.8	12.1	3.8	12.1	3.8	13.3	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.5	5.1	7.5	3.2	7.9	3.2	8.7	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.1	4.4	6.1	2.8	6.5	2.8	7.2	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.8	3.7	5.0	2.5	5.3	2.5	5.8	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.6	3.5	4.7	2.5	4.9	2.5	5.4	ns
$t_{dis}$	disable time	$\overline{OE}$ to Q; see <a href="#">Figure 10</a>	<a href="#">[4]</a>							
		$V_{CC} = 0.8 \text{ V}$	-	13.1	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	4.9	6.5	9.8	4.8	10.4	4.8	11.4	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.9	5.0	6.8	3.8	7.3	3.8	8.0	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	4.2	5.3	6.9	4.1	7.3	4.1	8.0	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	3.0	3.8	4.8	2.9	5.1	2.9	5.6	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	4.1	5.0	6.1	4.0	6.4	4.0	7.0	ns

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C				Unit	
			Min	Typ <sup>[1]</sup>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)		
<b><math>C_L = 30 \text{ pF}</math></b>											
$t_{pd}$	propagation delay	D to Q; see <a href="#">Figure 7</a>	<sup>[2]</sup>								
		$V_{CC} = 0.8 \text{ V}$	-	35.9	-	-	-	-	-	ns	
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	4.0	10.6	22.1	3.7	23.3	3.7	25.6	ns	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.6	7.5	12.3	3.5	13.6	3.5	15.0	ns	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.5	6.2	9.5	3.2	10.5	3.2	11.5	ns	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	3.3	5.1	6.9	2.9	7.6	2.9	8.3	ns	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	3.0	4.7	6.4	2.9	7.2	2.9	7.9	ns	
		LE to Q; see <a href="#">Figure 8</a>	<sup>[2]</sup>								
		$V_{CC} = 0.8 \text{ V}$	-	34.8	-	-	-	-	-	ns	
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.9	10.2	22.2	3.7	23.5	3.7	25.9	ns	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.5	7.2	12.4	3.4	13.7	3.4	15.1	ns	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.3	5.9	9.5	3.0	10.5	3.0	11.6	ns	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	3.1	4.8	6.8	2.7	7.5	2.7	8.2	ns	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.9	4.4	6.1	2.6	7.0	2.6	7.7	ns	
$t_{en}$	enable time	$\overline{OE}$ to Q; see <a href="#">Figure 10</a>	<sup>[3]</sup>								
		$V_{CC} = 0.8 \text{ V}$	-	34.5	-	-	-	-	-	ns	
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	5.5	9.1	16.2	4.9	16.2	4.9	17.8	ns	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	4.6	6.7	9.9	4.2	10.5	4.2	11.6	ns	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	4.2	5.7	7.9	3.7	8.6	3.7	9.5	ns	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	3.6	4.9	6.4	3.4	6.9	3.4	7.6	ns	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	3.4	4.7	6.1	3.3	6.5	3.3	7.2	ns	
$t_{dis}$	disable time	$\overline{OE}$ to Q; see <a href="#">Figure 10</a>	<sup>[4]</sup>								
		$V_{CC} = 0.8 \text{ V}$	-	19.2	-	-	-	-	-	ns	
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	8.0	9.9	13.7	7.9	14.5	7.9	16.0	ns	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	6.3	7.7	9.7	6.2	10.5	6.2	11.6	ns	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	7.3	8.7	10.6	7.2	11.3	7.2	12.4	ns	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	5.2	6.2	7.5	5.1	7.8	5.1	8.6	ns	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	7.5	8.8	10.2	7.4	10.5	7.4	11.6	ns	
<b><math>C_L = 5 \text{ pF, } 10 \text{ pF, } 15 \text{ pF and } 30 \text{ pF}</math></b>											
$t_w$	pulse width	LE HIGH; see <a href="#">Figure 8</a>									
		$V_{CC} = 0.8 \text{ V}$	-	4.0	-	-	-	-	-	ns	
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	0.7	-	2.1	-	2.1	-	ns	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	0.5	-	1.3	-	1.3	-	ns	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	0.4	-	1.0	-	1.0	-	ns	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	0.3	-	0.8	-	0.8	-	ns	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	-	0.2	-	0.8	-	0.8	-	ns	

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	
$t_{su(H)}$	set-up time HIGH	D to LE; see <a href="#">Figure 9</a>							
		$V_{CC} = 0.8 \text{ V}$	-	4.6	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	0.9	-	2.2	-	2.2	-
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	0.6	-	1.4	-	1.4	-
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	0.4	-	1.0	-	1.0	-
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	0	-	0.6	-	0.6	-
$t_{su(L)}$	set-up time LOW	D to LE; see <a href="#">Figure 9</a>							
		$V_{CC} = 0.8 \text{ V}$	-	4.0	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	1.2	-	2.7	-	2.7	-
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	0.7	-	1.5	-	1.5	-
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	0.6	-	1.2	-	1.2	-
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	0.4	-	0.9	-	0.9	-
$t_h$	hold time	D to LE HIGH or LOW; see <a href="#">Figure 9</a>							
		$V_{CC} = 0.8 \text{ V}$	-	−4.6	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	−0.9	-	−0.1	-	−0.1	-
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	−0.6	-	−0.1	-	−0.1	-
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	−0.4	-	0	-	0	-
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	−0.2	-	0.2	-	0.2	-
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	-	−0.1	-	0.3	-	0.3	-

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C				Unit
			Min	Typ <sup>[1]</sup>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C <sub>PD</sub>	power dissipation capacitance	f <sub>i</sub> = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[5][6]</sup>								
		output enabled								
		V <sub>CC</sub> = 0.8 V	-	2.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	2.1	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	2.4	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	2.8	-	-	-	-	-	pF

[1] All typical values are measured at nominal V<sub>CC</sub>.[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.[3] t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>.[4] t<sub>dis</sub> is the same as t<sub>PHZ</sub> and t<sub>PLZ</sub>.

[5] All specified values are the average typical values over all stated loads.

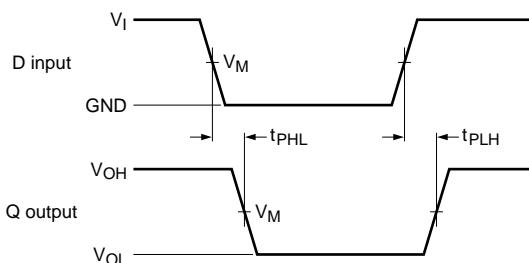
[6] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f<sub>i</sub> = input frequency in MHz;f<sub>o</sub> = output frequency in MHz;C<sub>L</sub> = output load capacitance in pF;V<sub>CC</sub> = supply voltage in V; $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs;

N = number of inputs switching.

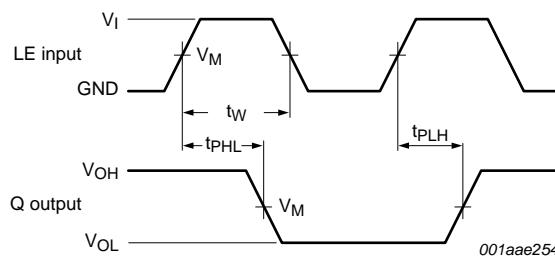
## 12. Waveforms



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Measurement points are given in [Table 9](#).Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

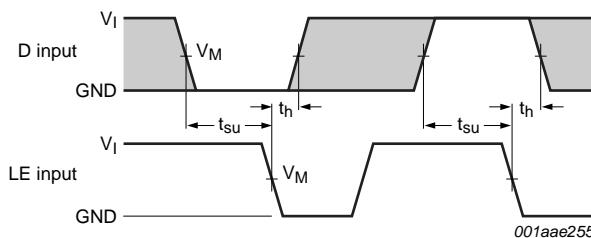
Fig 7. The data input (D) to output (Q) propagation delays



Measurement points are given in [Table 9](#).

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 8. The latch enable input (LE) to output (Q) propagation delays, the latch enable input (LE) pulse width**



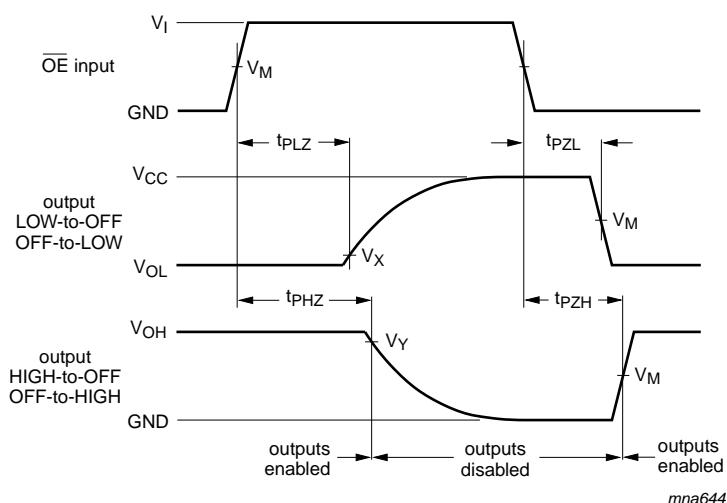
Measurement points are given in [Table 9](#).

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 9. Data set-up and hold times for the D input to the LE input**

**Table 9. Measurement points**

Supply voltage	Output	Input		
$V_{CC}$ 0.8 V to 3.6 V	$V_M$ $0.5 \times V_{CC}$	$V_M$ $0.5 \times V_{CC}$	$V_I$ $V_{CC}$	$t_r = t_f$ $\leq 3.0 \text{ ns}$



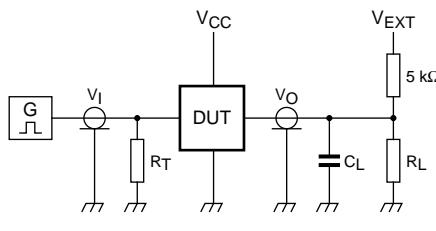
Measurement points are given in [Table 10](#).

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 10. Turn-on and turn-off times**

**Table 10. Measurement points**

Supply voltage	Input	Output		
$V_{CC}$	$V_M$	$V_M$	$V_X$	$V_Y$
0.8 V to 1.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.1$ V	$V_{OH} - 0.1$ V
1.65 V to 2.7 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15$ V	$V_{OH} - 0.15$ V
3.0 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.3$ V	$V_{OH} - 0.3$ V



Test data is given in [Table 11](#).

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

**Fig 11. Test circuit for measuring switching times**

**Table 11. Test data**

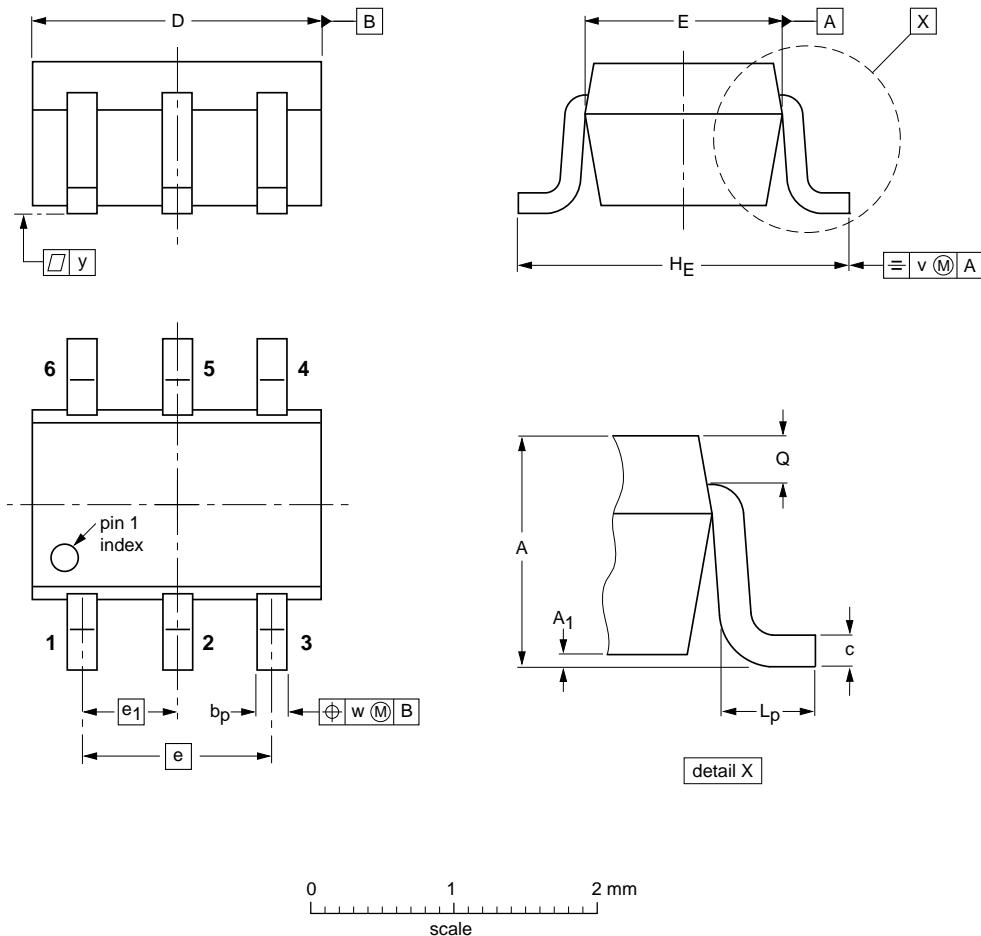
Supply voltage	Load		$V_{EXT}$		
$V_{CC}$	$C_L$	$R_L$ <sup>[1]</sup>	$t_{PLH}, t_{PHL}$	$t_{PZH}, t_{PHZ}$	$t_{PZL}, t_{PLZ}$
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L = 1 \text{ M}\Omega$ .

## 13. Package outline

Plastic surface-mounted package; 6 leads

SOT363



### DIMENSIONS (mm are the original dimensions)

UNIT	A	$A_1$ max	$b_p$	c	D	E	e	$e_1$	$H_E$	$L_p$	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT363			SC-88			04-11-08 06-03-16

Fig 12. Package outline SOT363 (SC-88)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body  $1 \times 1.45 \times 0.5$  mm

SOT886

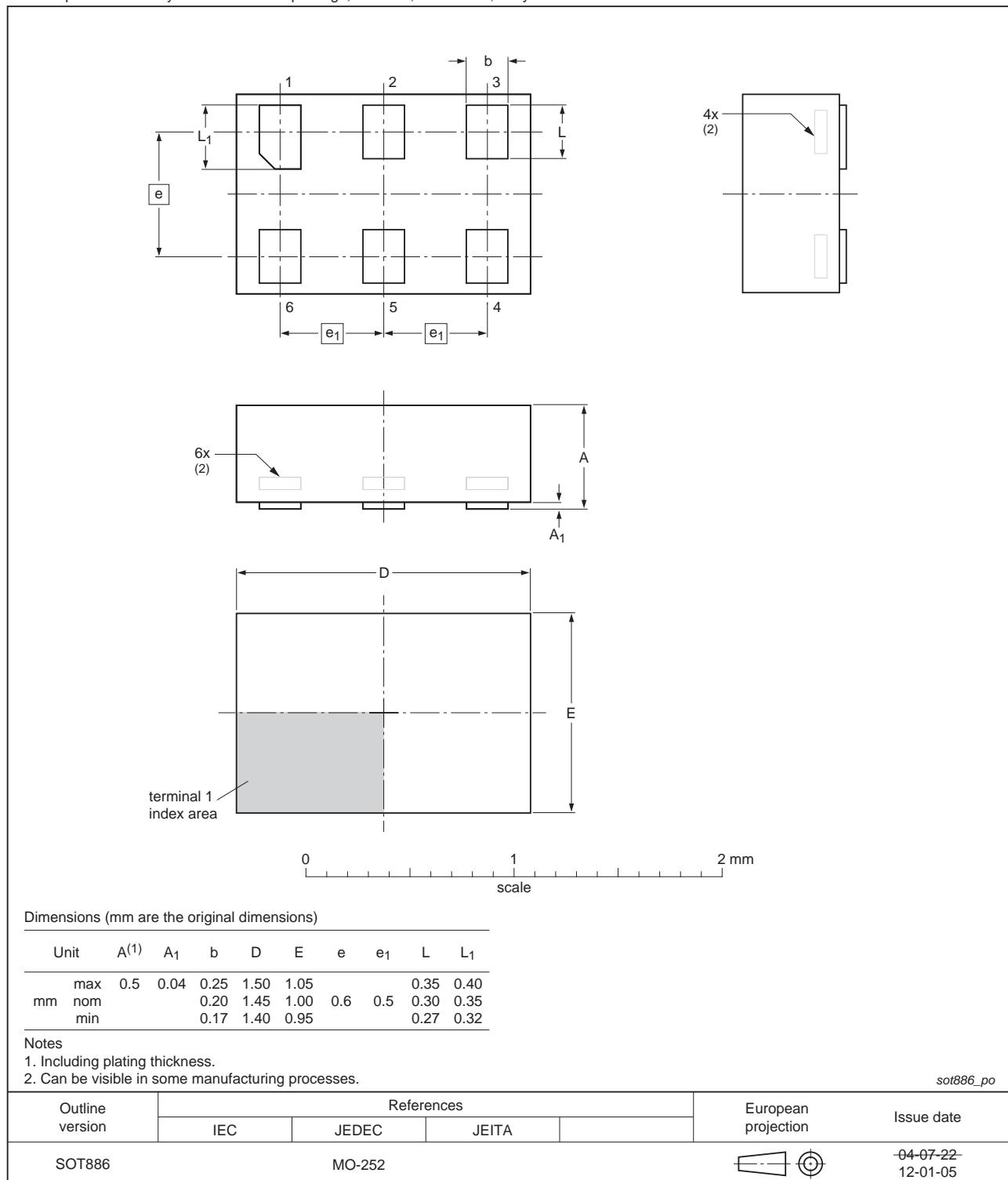
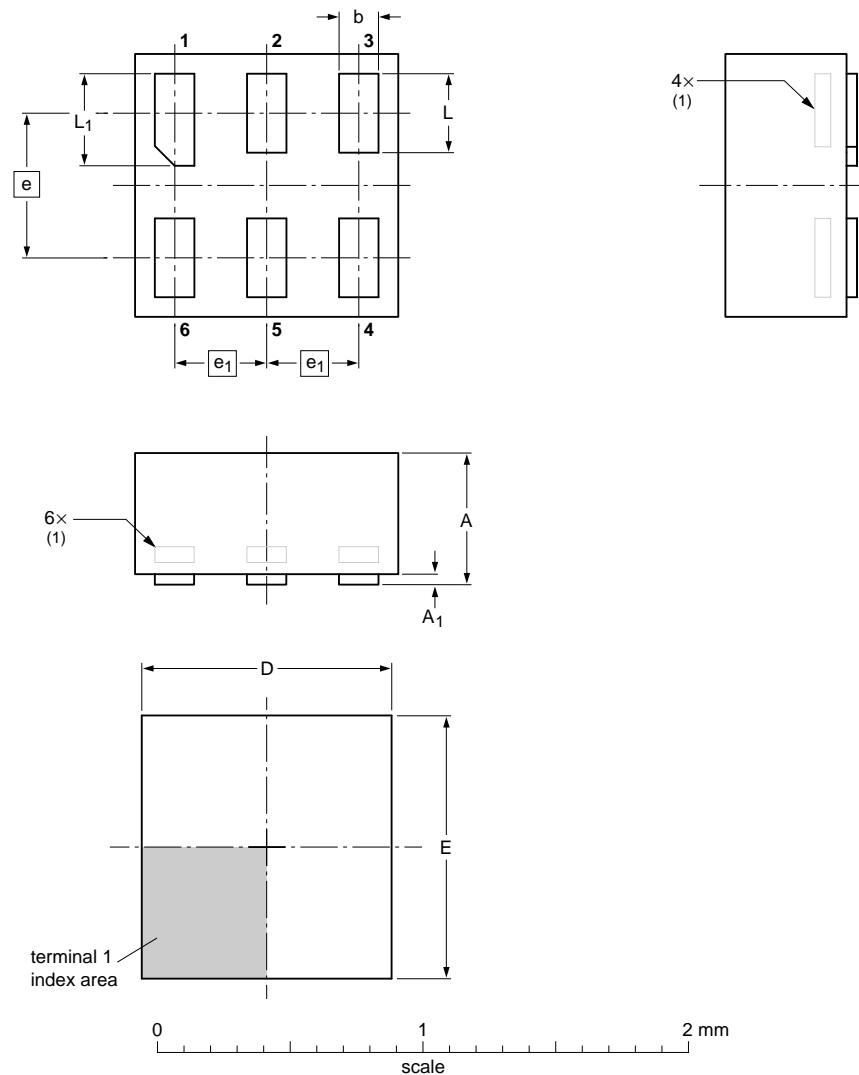


Fig 13. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891



## DIMENSIONS (mm are the original dimensions)

UNIT	A <sub>max</sub>	A <sub>1max</sub>	b	D	E	e	e <sub>1</sub>	L	L <sub>1</sub>
mm	0.5	0.04	0.20 0.12	1.05 0.95	1.05 0.95	0.55	0.35	0.35 0.27	0.40 0.32

## Note

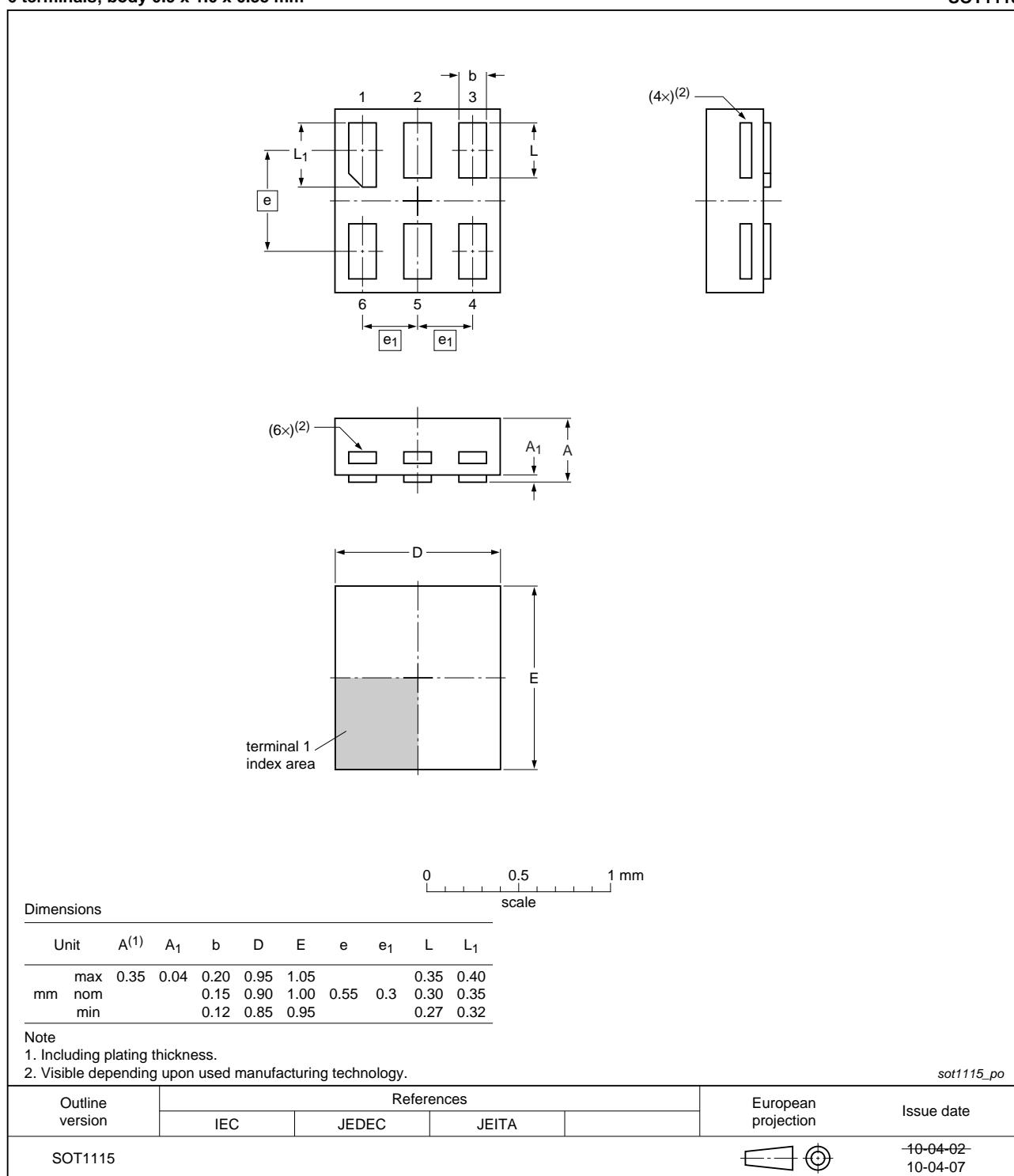
1. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT891						05-04-06 07-05-15

Fig 14. Package outline SOT891 (XSON6)

**XSON6: extremely thin small outline package; no leads;  
6 terminals; body 0.9 x 1.0 x 0.35 mm**

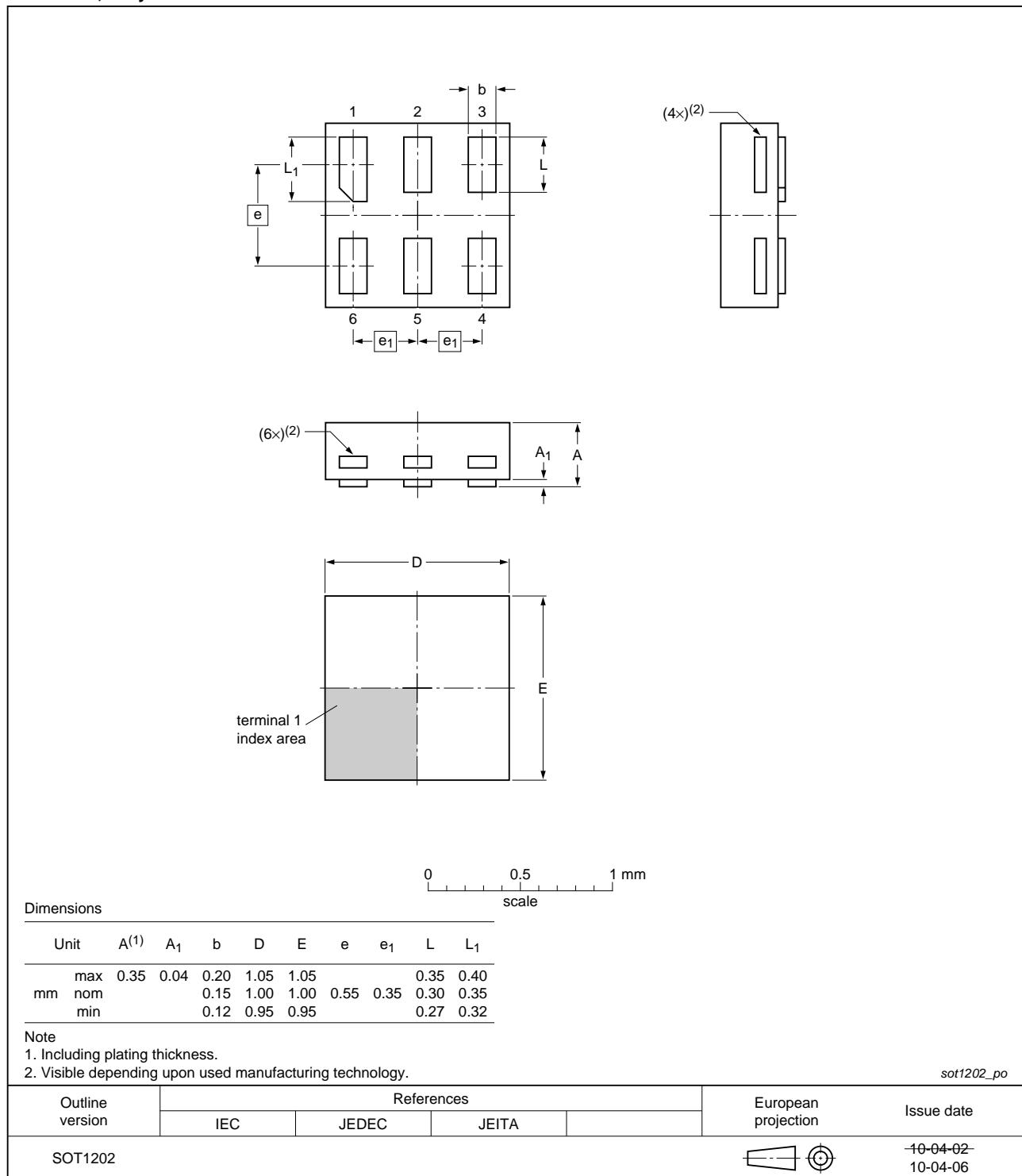
SOT1115



**Fig 15. Package outline SOT1115 (XSON6)**

**XSON6: extremely thin small outline package; no leads;  
6 terminals; body 1.0 x 1.0 x 0.35 mm**

SOT1202



**Fig 16. Package outline SOT1202 (XSON6)**

## 14. Abbreviations

**Table 12. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

## 15. Revision history

**Table 13. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G373 v.6	20120704	Product data sheet	-	74AUP1G373 v.5
Modifications:		• Package outline drawing of SOT886 ( <a href="#">Figure 13</a> ) modified.		
74AUP1G373 v.5	20111125	Product data sheet	-	74AUP1G373 v.4
Modifications:		• Legal pages updated.		
74AUP1G373 v.4	20100715	Product data sheet	-	74AUP1G373 v.3
74AUP1G373 v.3	20080109	Product data sheet	-	74AUP1G373 v.2
74AUP1G373 v.2	20070720	Product data sheet	-	74AUP1G373 v.1
74AUP1G373 v.1	20061129	Product data sheet	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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